CMOS Digital Integrated Circuits Silicon Monolithic

# TC7WH32FU

#### 1. Functional Description

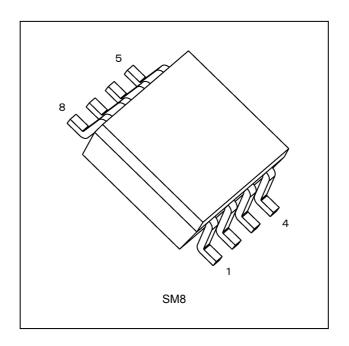
• Dual 2-Input OR Gate

#### 2. Features

- (1) Wide operating temperature range:  $T_{opr} = -40$  to 125 °C (Note 1)
- (2) High speed operation:  $t_{pd}$  = 3.8 ns (typ.) (V<sub>CC</sub> = 5.0 V, C<sub>L</sub> = 15 pF)
- (3) Low power dissipation:  $I_{CC} = 2.0 \ \mu A \ (max) \ (T_a = 25 \ ^\circ C)$
- (4) High noise immunity:  $V_{\text{NIH}} = V_{\text{NIL}} = 28 \% V_{\text{CC}}$  (min)
- (5) Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$
- (6) 5.5 V tolerant inputs
- (7) Wide operating voltage range:  $V_{CC} = 2.0$  to 5.5 V
- (8) Identical pin assignment and function with TC7W32

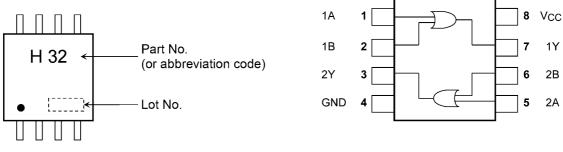
Note 1: For devices with the ordering part number ending in J(CT.  $T_{opr}$  = -40 to 85 °C for the other devices.

#### 3. Packaging



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## 4. Marking and Pin Assignment



Marking



#### 5. IEC Logic Symbol



#### 6. Truth Table

А	В	Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

## 7. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>		-0.5 to 7.0	]
DC output voltage	V <sub>OUT</sub>		-0.5 to V <sub>CC</sub> + 0.5	
Input diode current	I <sub>IK</sub>		-20	mA
Output diode current	I <sub>OK</sub>	(Note 1)	±20	]
DC output current	I <sub>OUT</sub>		±25	]
V <sub>CC</sub> /ground current	I <sub>CC</sub>		±50	
Power dissipation	PD		300	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{OUT}$  < GND,  $V_{OUT}$  >  $V_{CC}$ 

## 8. Operating Ranges (Note)

Characteristics	Symbol	Note	Test Condition	Rating	Unit
Supply voltage	V <sub>CC</sub>		—	2.0 to 5.5	V
Input voltage	V <sub>IN</sub>		—	0 to 5.5	
Output voltage	V <sub>OUT</sub>		—	0 to V <sub>CC</sub>	
Operating temperature	T <sub>opr</sub>	(Note 1)	—	-40 to 125	°C
		(Note 2)	—	-40 to 85	
Input rise and fall time	dt/dv		$V_{CC} = 3.3 \pm 0.3 \text{ V}$	0 to 100	ns/V
			$V_{CC}$ = 5.0 ± 0.5 V	0 to 20	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.

Note 1: For devices with the ordering part number ending in J(CT.

Note 2: For devices except those with the ordering part number ending in J(CT.

#### 9. Electrical Characteristics

## 9.1. DC Characteristics (Unless otherwise specified, Ta = 25 °C)

Characteristics	Symbol	Test Condition	l	V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	—		2.0	1.5	_	—	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	_	
Low-level input voltage	VIL	—		2.0	—	_	0.5	V
				3.0 to 5.5	_	_	$V_{CC} \times 0.3$	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = -50 μA	2.0	1.9	2.0	_	V
				3.0	2.9	3.0	—	
				4.5	4.4	4.5	_	
			I <sub>OH</sub> = -4 mA	3.0	2.58	_	_	
			I <sub>OH</sub> = -8 mA	4.5	3.94		-	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	—	0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I <sub>OL</sub> = 4 mA	3.0	_	_	0.36	
			I <sub>OL</sub> = 8 mA	4.5	_	_	0.36	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	—		±0.1	μA
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND		5.5	_		2.0	μA

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#### 9.2. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

Characteristics	Symbol	Test Condi	ition	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	—		2.0	1.5	—	V
				3.0 to 5.5	$V_{CC} \times 0.7$	—	
Low-level input voltage	VIL	_		2.0	—	0.5	V
				3.0 to 5.5	_	$V_{CC} \times 0.3$	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = -50 μA	2.0	1.9	—	V
				3.0	2.9	—	
				4.5	4.4	—	
			I <sub>OH</sub> = -4 mA	3.0	2.48	—	
			I <sub>OH</sub> = -8 mA	4.5	3.80	_	
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IL}$	I <sub>OL</sub> = 50 μA	2.0	—	0.1	V
				3.0	—	0.1	
				4.5	—	0.1	
			I <sub>OL</sub> = 4 mA	3.0	_	0.44	
			I <sub>OL</sub> = 8 mA	4.5	_	0.44	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±1.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	20.0	μA

## 9.3. DC Characteristics (Note) (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C)

Characteristics	Symbol	Test Con	dition	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		2.0	1.5	—	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	
Low-level input voltage	VIL	_		2.0	_	0.5	V
				3.0 to 5.5	—	$V_{CC} \times 0.3$	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = -50 μA	2.0	1.9	—	V
				3.0	2.9	_	
				4.5	4.4	—	
			I <sub>OH</sub> = -4 mA	3.0	2.40	—	
			I <sub>OH</sub> = -8 mA	4.5	3.70	—	
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IL}$	I <sub>OL</sub> = 50 μA	2.0	—	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I <sub>OL</sub> = 4 mA	3.0	—	0.55	
			I <sub>OL</sub> = 8 mA	4.5	_	0.55	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±2.0	μA
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	40.0	μA

Note: For devices with the ordering part number ending in J(CT.

#### 9.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		—	$\textbf{3.3}\pm\textbf{0.3}$	15	_	5.5	7.9	ns
					50	_	8.0	11.4	
				$5.0\pm0.5$	15	_	3.8	5.5	
					50	_	5.3	7.5	
Input capacitance	C <sub>IN</sub>		_			_	4	10	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 1)	—			_	14	—	pF

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.  $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per 1 gate)}$ 

#### 9.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	—	$\textbf{3.3}\pm\textbf{0.3}$	15	1.0	9.5	ns
				50	1.0	13.0	
			$5.0\pm0.5$	15	1.0	6.5	
				50	1.0	8.5	
Input capacitance	C <sub>IN</sub>	—			—	10	pF

## 9.6. AC Characteristics (Note) (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	$C_L (pF)$	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	—	$\textbf{3.3}\pm\textbf{0.3}$	15	1.0	11.0	ns
				50	1.0	14.5	
			$5.0\pm0.5$	15	1.0	7.5	
				50	1.0	9.5	
Input capacitance	C <sub>IN</sub>	—			_	10	pF

Note: For devices with the ordering part number ending in J(CT.

#### 9.7. Noise Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

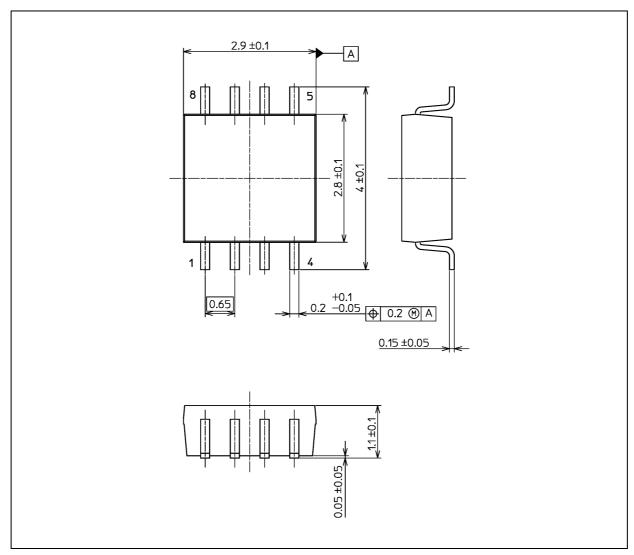
Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	0.3	0.8	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-0.3	-0.8	V
Minimum high-level dynamic input voltage	V <sub>IHD</sub>	C <sub>L</sub> = 50 pF	5.0	_	3.5	V
Maximum low-level dynamic input voltage	V <sub>ILD</sub>	C <sub>L</sub> = 50 pF	5.0	_	1.5	V



## TC7WH32FU

#### **Package Dimensions**

Unit: mm



Weight: 21 mg (typ.)

	Package Name(s)
JEDEC: SOT-505	
Nickname: SM8	

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